## NSN 5961-01-258-3480

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-258-3480 **Inclosure Material:** Plastic **Overall Length:** 0.380 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.210 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 420.0 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes forward current, total rms nanoamperes **Power Rating Per Characteristic:** 1500.0 watts small-signal input power, common-emitter megahertz **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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